



HD75160A

Octal General Purpose Interface Bus Transceivers

REJ03D0308-0200Z

(Previous ADE-205-590 (Z))

Rev.2.00

Jul.16.2004

Description

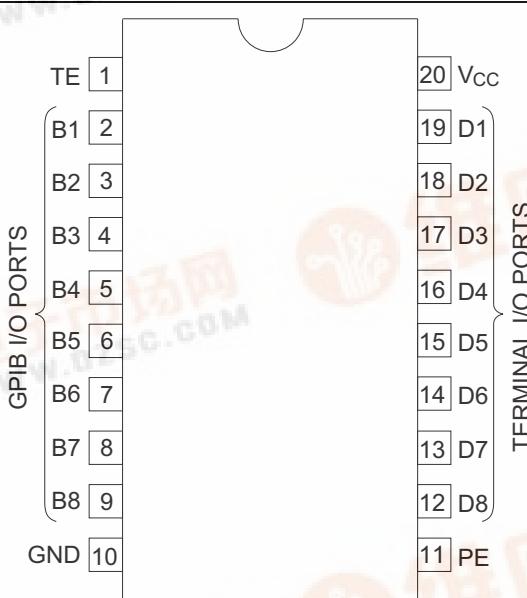
The HD75160A is an 8 channel general purpose interface bus transceiver designed to meet the requirements of IEEE standard 488-1978. The transceiver features driver outputs which can handle loads up to 48 mA of sink current if talk Enable(TE) is high, the ports have the characteristics of open collector outputs when pull up enable(PE) is low, and of three state outputs when PE is high. Taking TE low places the ports in the high impedance state. The device exhibits a high impedance to the bus when $V_{CC} = 0$ V since the bus terminating resistors are built in when combined with the HD75161A management bus transceivers, the pair provides the complete 16 wire interface for the IEEE-488 bus.

Features

- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD75160AP	DILP-20 pin	DP-20N, -20NEV	P	—

Pin Arrangement



(Top view)

Function Table

Drivers			Receivers				Output D	
Input			Output B	Input				
D	TE	PE		B	TE	PE		
H	H	H	H	L	L	X	L	
L	H	X	L	H	L	X	H	
H	X	L	Z ^{*1}	X	H	X	Z	
X	L	X	Z ^{*1}					

H : High level

L : Low level

X : Irrelevant

Z : High impedance

Note: 1. This is the high impedance state of a normal three state output modified by the internal resistors to V_{CC} and ground.

Absolute Maximum Ratings

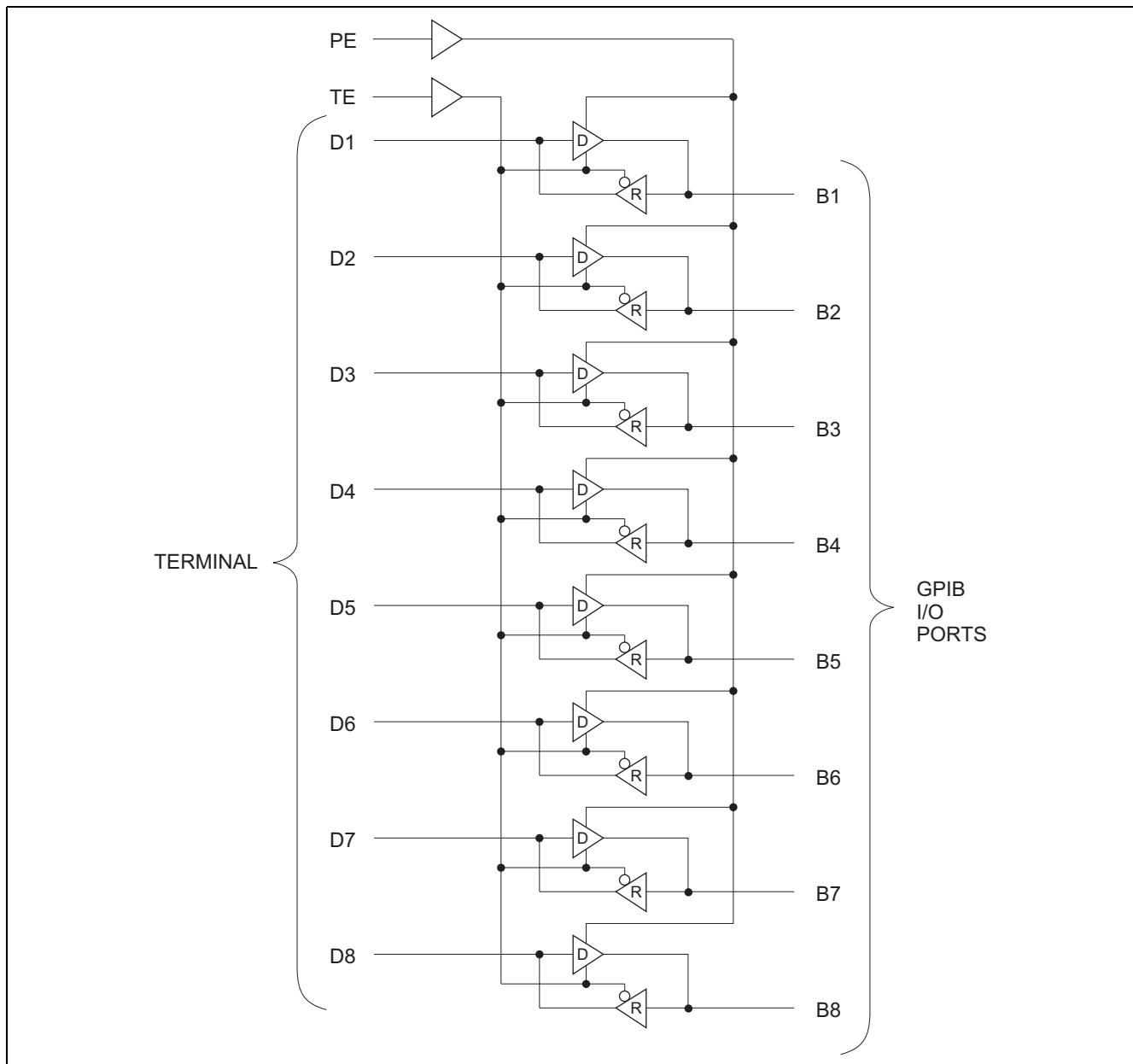
Item	Symbol	Rating	Unit
Supply Voltage	V _{CC}	7	V
Input Voltage	V _{IN}	5.5	V
Output Current	I _{OL}	100	mA
Power Dissipation (Ta = 25°C)	P _T	1150	mW
Operating temperature range	Topr	0 to 70	°C
Storage Temperature Range	Tstg	-65 to +150	°C

Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit
Supply Voltage	V _{CC}	4.75	5.00	5.25	V
Output Current	I _{OH}	—	—	-5.2	mA
		—	—	-800	μA
Output Current	I _{OL}	—	—	48	mA
		—	—	16	
Operating Temperature	Topr	0	—	70	°C

Logic Diagram



DC Electrical Characteristics (Ta = 0 to 70°C)

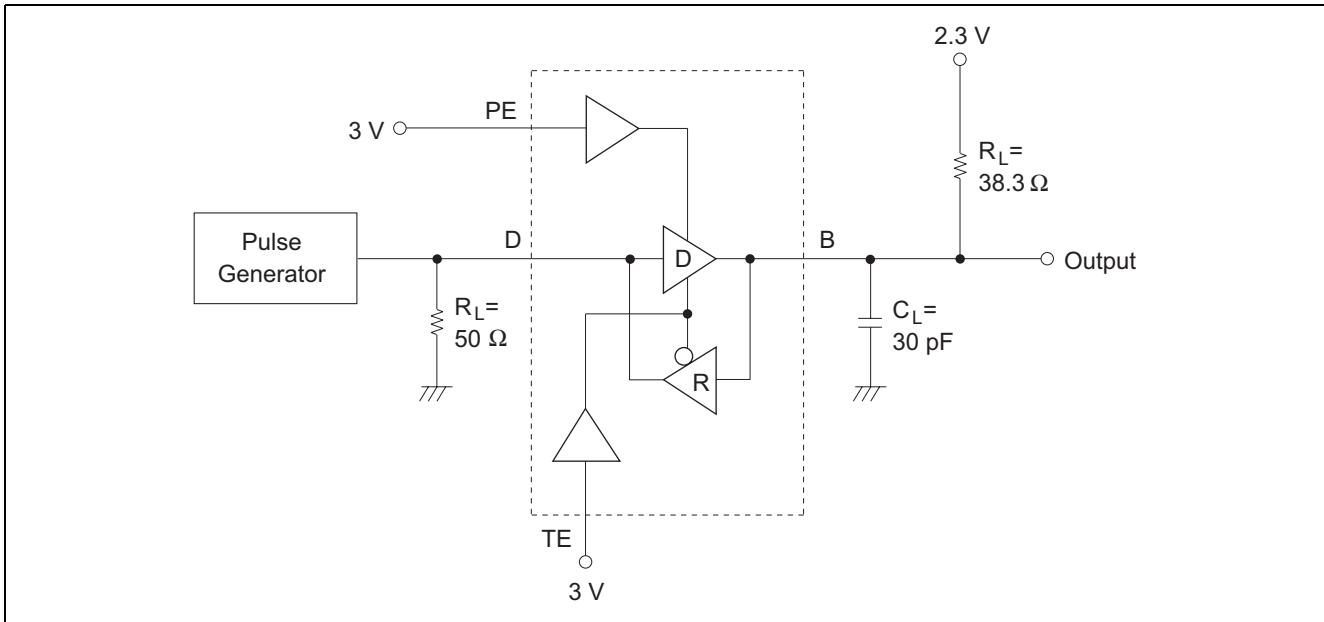
Item		Symbol	V _{CC}	Min	Max	Unit	Conditions		
Input Voltage		V _{IH}	2	—	—	V			
		V _{IL}	—	—	0.8				
Input Clamp Voltage	V _{IK}	—	—	-1.5	V	I _I = -18 mA			
Hysteresis	Bus	V _T ⁺ - V _T ⁻	0.4	—	—	V			
I/O Output Voltage	Terminal	V _{OH}	2.7	—	—	V	I _{OH} = -800 µA, TE at 0.8 V		
	Bus		2.5	—	—		I _{OH} = -5.2 mA, PE and TE at 2 V		
	Terminal	V _{OL}	—	—	0.5	V	I _{OL} = 16 mA, TE at 0.8 V		
	Bus		—	—	0.5		I _{OL} = 48 mA, TE at 2 V		
Input Current	Terminal	I _I	—	—	100	µA	V _I = 5.5 V		
		I _{IH}	—	—	20		V _I = 2.7 V		
		I _{IL}	—	—	-100		V _I = 0.5 V		
Voltage At Bus Port		V _{I/O (bus)}	2.5	—	3.7	V	Driver	I _{I(bus)} = 0	
			—	—	-1.5			I _{I(bus)} = -12 mA	
Current Into Bus Port	V _{CC} ON	I _{I/O (bus)}	-1.3	—	—	mA	Driver	V _{I(bus)} = -1.5 V to 0.4 V	
			0	—	-3.2			V _{I(bus)} = 0.4 V to 2.5 V	
			—	—	+2.5			V _{I(bus)} = 2.5 V to 3.7 V	
			—	—	-3.2			V _{I(bus)} = 3.7 V to 5 V	
			0	—	2.5			V _{I(bus)} = 5 V to 5.5 V	
			0.7	—	2.5			V _{CC} = 0, V _{I(bus)} = 0 V to 2.5 V	
Short circuit Output Current	Terminal	I _{OS}	-15	—	-75	mA			
	Bus		-25	—	-125				
Supply Voltage		I _{CC}	—	60	80	mA	No Load, Receivers Low and Enabled		
			—	75	100			No Load, Drivers Low and Enabled	
Busport Capacitance	C _{I/O (bus)}	—	30	—	—	pF	V _{CC} = 5 V or 0 V, V _{I/O} = 0 to 2 V, f = 1 MHz		

Note: 1. V_{CC} = 5 V, Ta = 25°CSwitching Characteristics (V_{CC} = 5 V, Ta = 25°C)

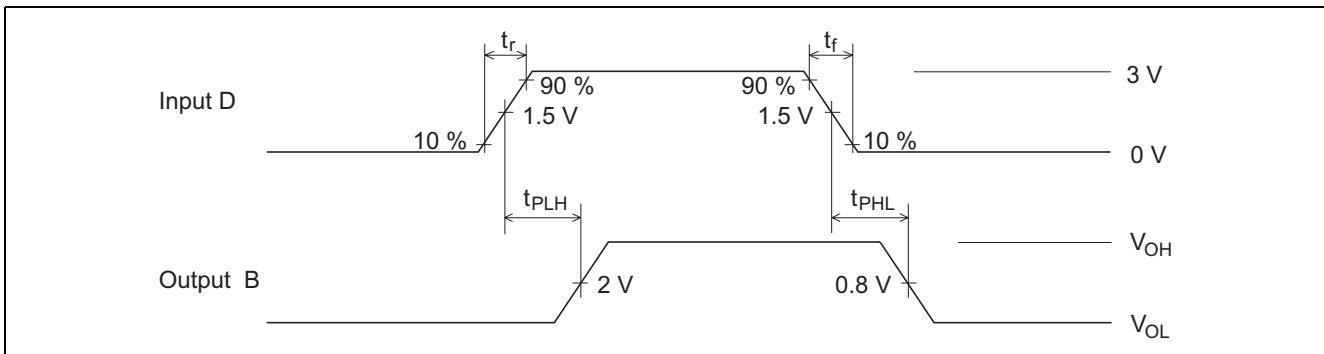
Item	Symbol	Input	Output	Min	Typ	Max	Unit	Test Circuit	Conditions
Propagation Delay Time	t _{PLH}	Terminal	BUS	—	14	20	ns	1	C _L = 30 pF R _L = 38.3 Ω to 2.3 V
	t _{PHL}			—	14	20			C _L = 30 pF R _L = 240 Ω to 5 V
	t _{PLH}	BUS	Terminal	—	12	20		2	C _L = 30 pF R _L = 240 Ω to 5 V
	t _{PHL}			—	16	22			C _L = 30 pF R _L = 240 Ω to 5 V
Output Enable Time	t _{ZH}	TE	BUS	—	25	35		3	C _L = 15 pF R _L = 480 Ω to 0 V
Output Disable Time	t _{HZ}			—	13	22			C _L = 15 pF R _L = 38.3 Ω to 2.3 V
Output Enable Time	t _{ZL}			—	22	35			C _L = 15 pF R _L = 38.3 Ω to 2.3 V
Output Disable Time	t _{LZ}			—	22	32			C _L = 15 pF R _L = 38.3 Ω to 2.3 V
Output Enable Time	t _{ZH}	TE	Terminal	—	20	30		4	C _L = 15 pF R _L = 3 kΩ to 0 V
Output Disable Time	t _{HZ}			—	12	20			C _L = 15 pF R _L = 280 Ω to 5 V
Output Enable Time	t _{ZL}			—	23	32			C _L = 15 pF R _L = 280 Ω to 5 V
Output Disable Time	t _{LZ}			—	19	30			C _L = 15 pF R _L = 280 Ω to 5 V
Output Pull up Enable Time	t _{en}	PE	BUS	—	15	22		5	C _L = 15 pF R _L = 480 Ω to 0 V
Output Pull up Disable Time	t _{dis}			—	13	20			C _L = 15 pF R _L = 480 Ω to 0 V

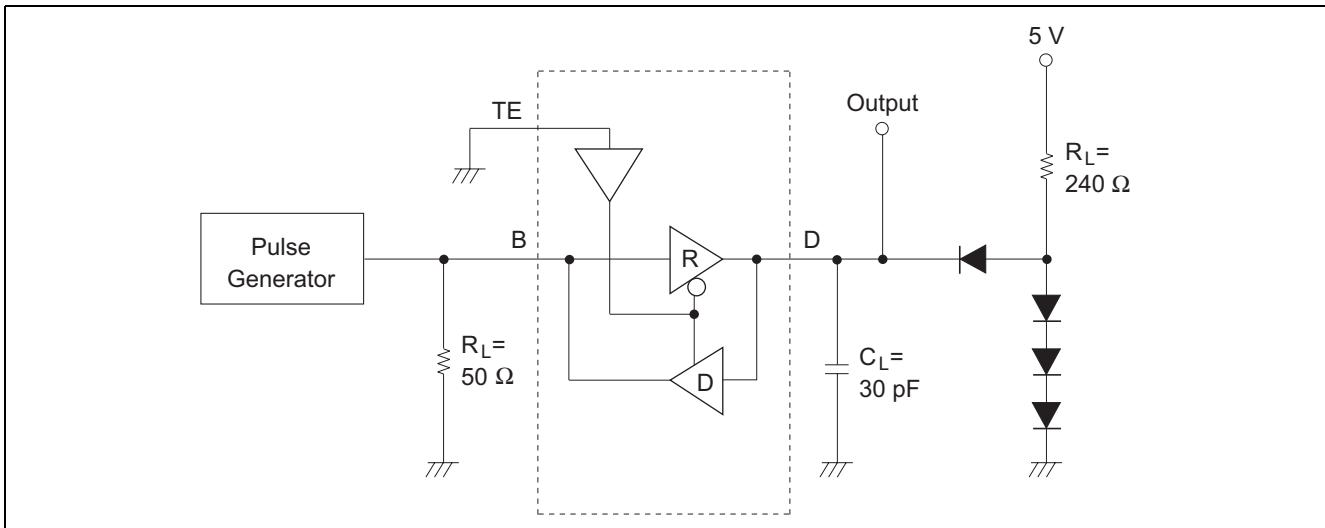
Switching Time Test Method

1. t_{PLH}, t_{PHL}

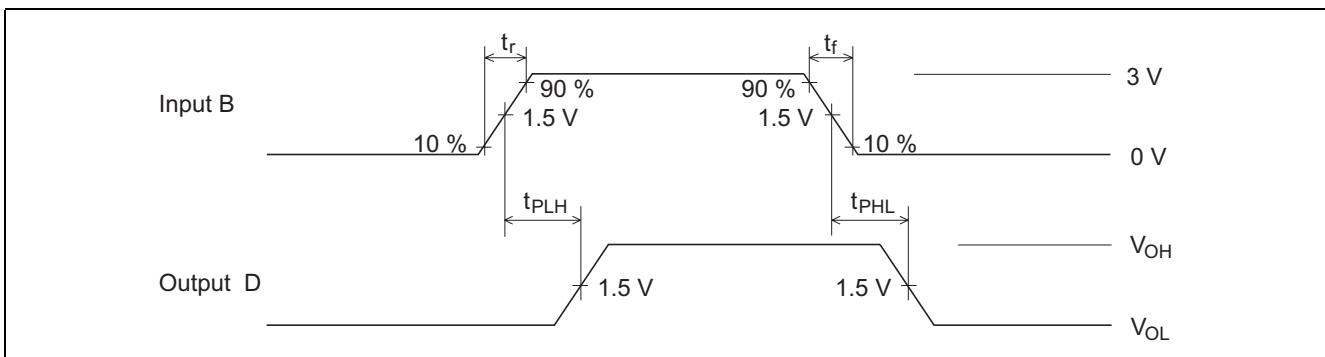


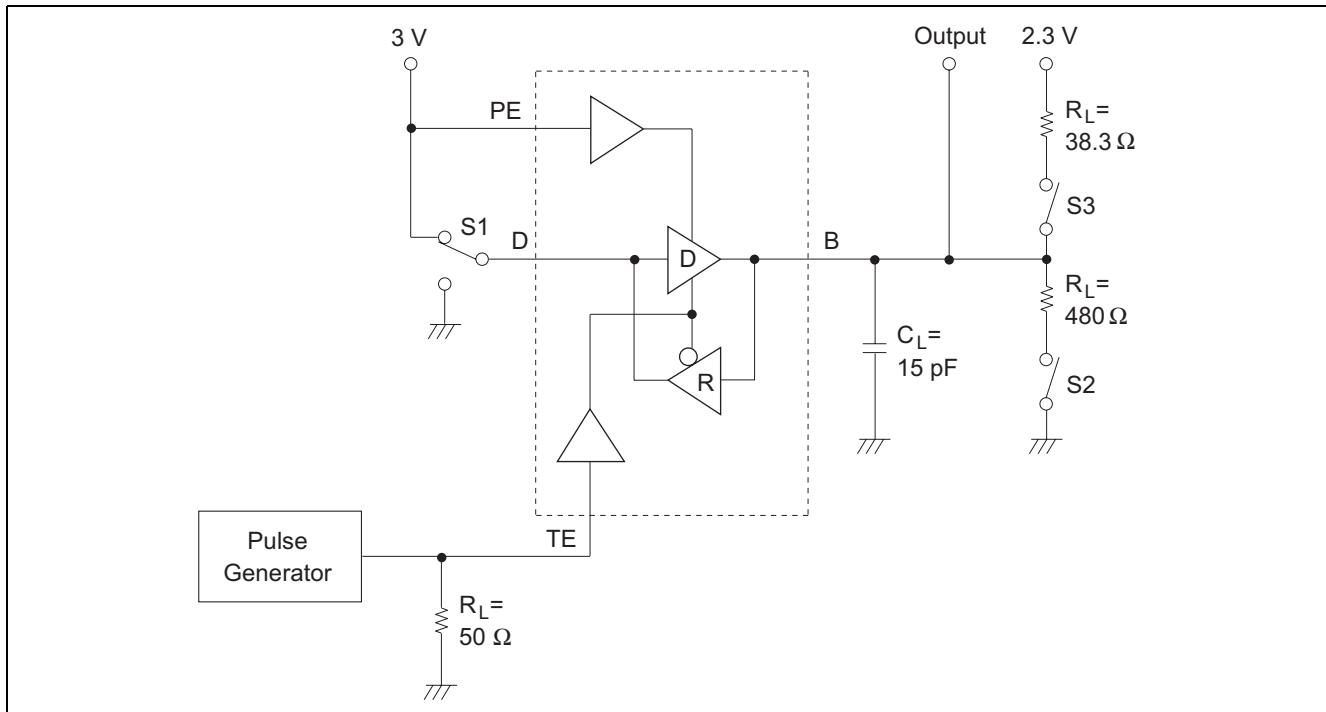
Waveforms-1



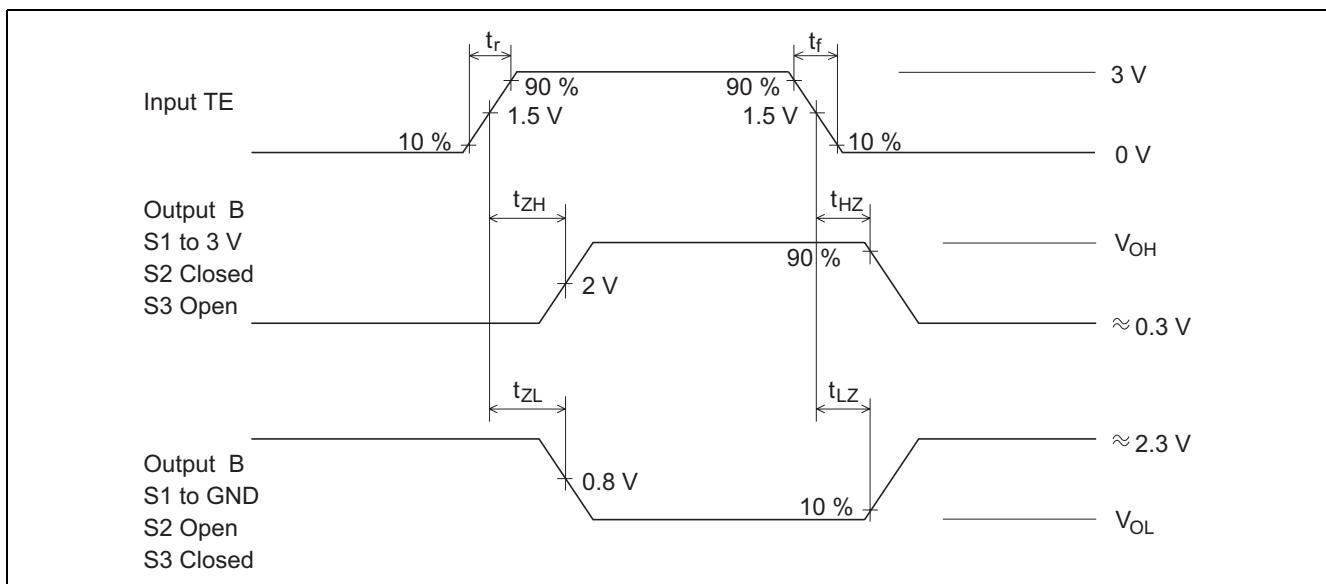
2. t_{PLH}, t_{PHL} 

Waveforms-2

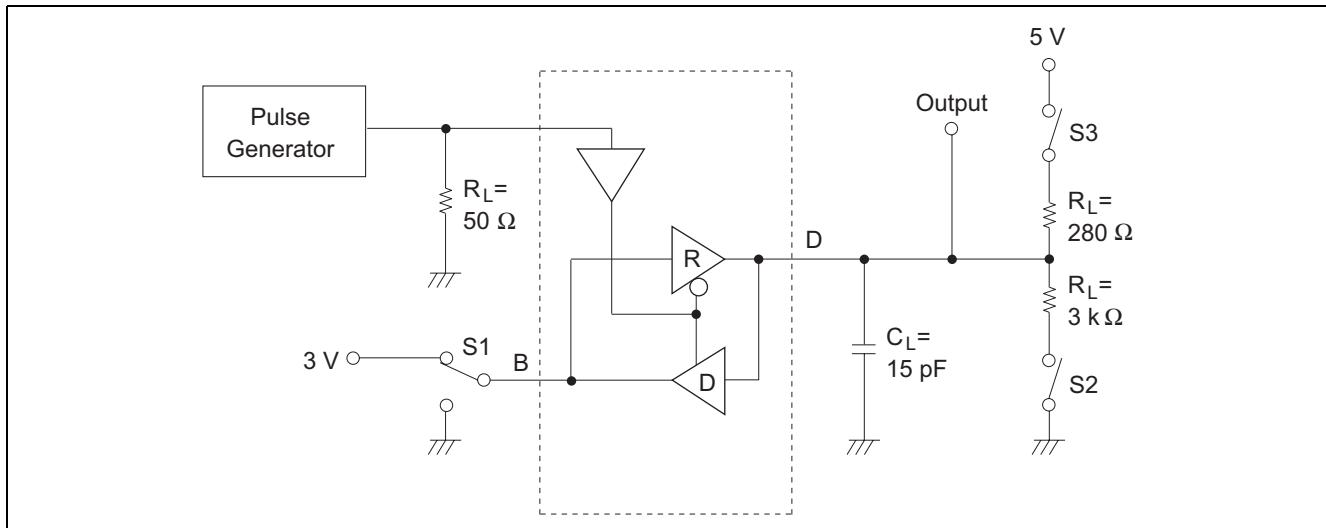


3. t_{ZH} , t_{HZ} , t_{ZL} , t_{LZ} 

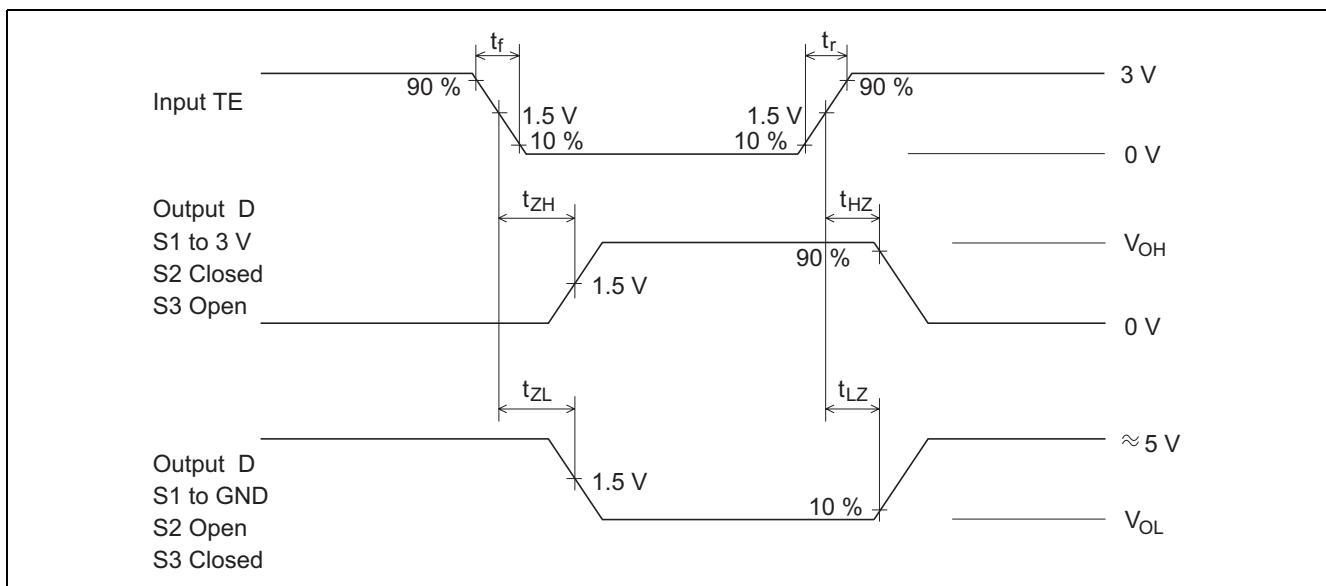
Waveforms-3

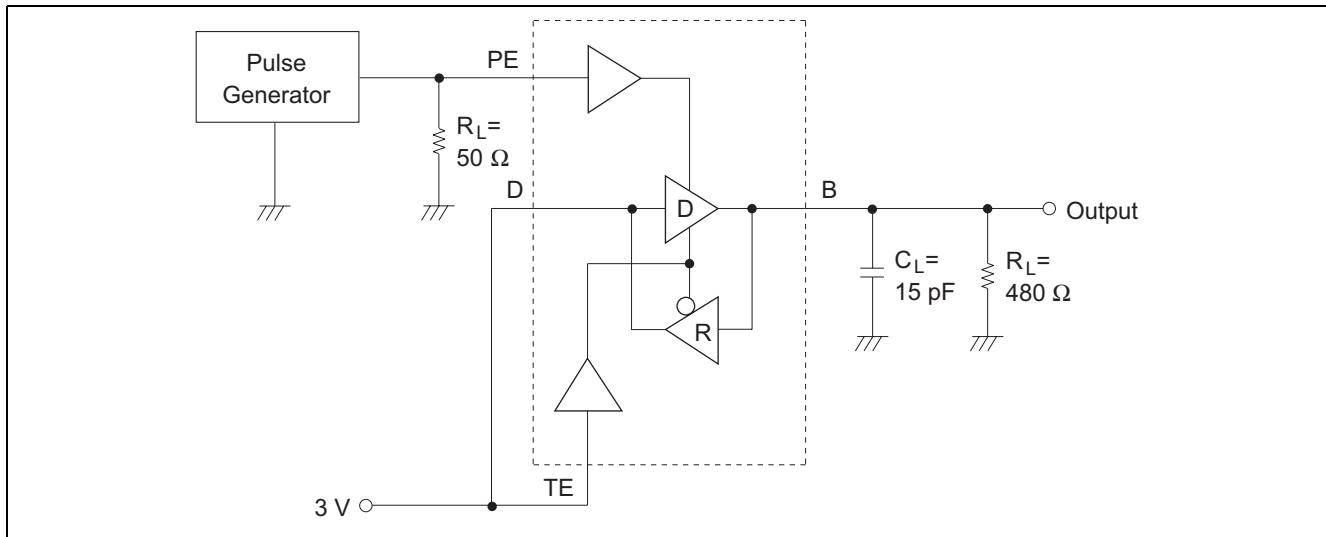


4. t_{ZH} , t_{HZ} , t_{ZL} , t_{LZ}

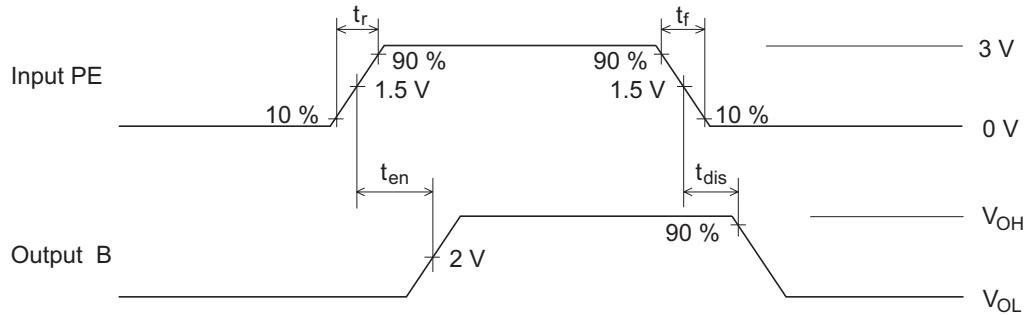


Waveforms-4



5. t_{en} , t_{dis} 

Waveforms-5

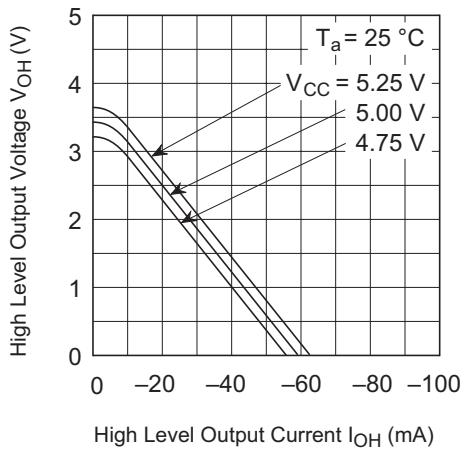


Notes:

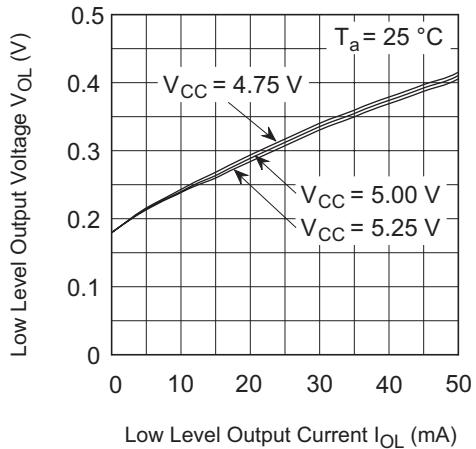
1. The pulse generator has the following characteristics:
PRR = 1 MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_{out} = 50 \Omega$
2. C_L includes probe and jig capacitance.
3. All diodes are 1S2074(H).

Characteristics Of Driver And Receiver

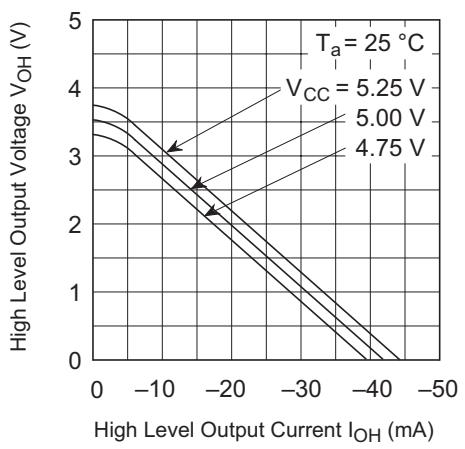
(a) Driver Output



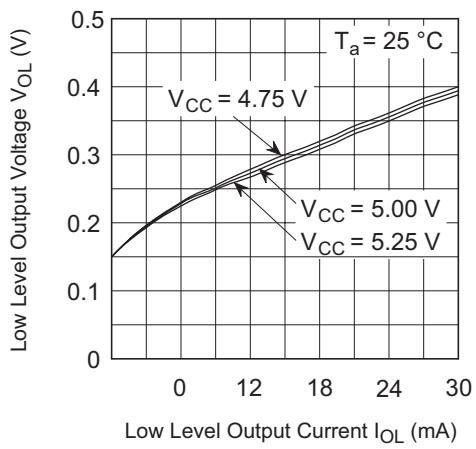
(b) Driver Output



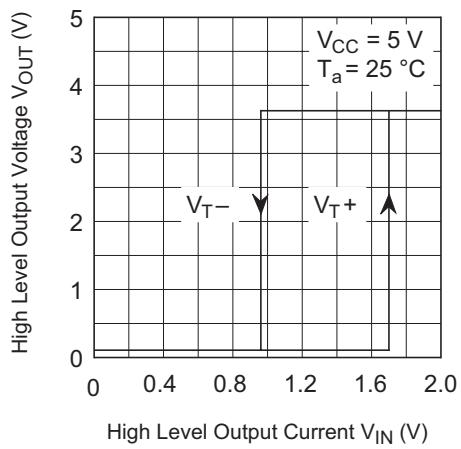
(c) Receiver Output



(d) Receiver Output

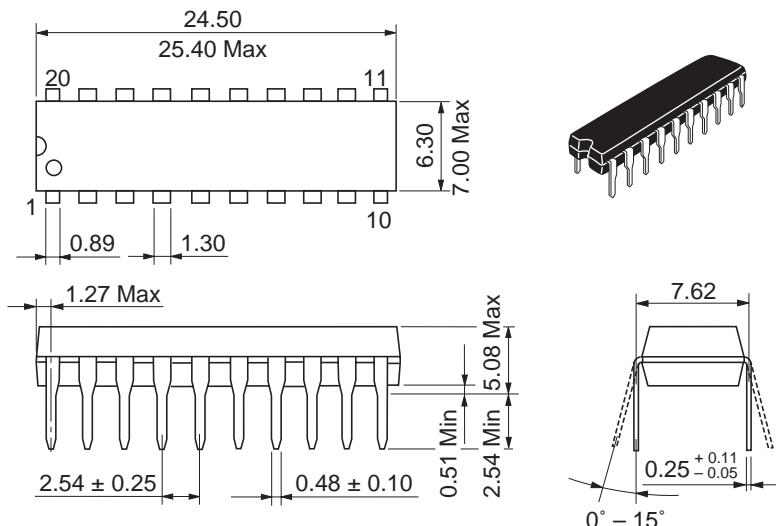


(e) Input / Output Characteristics at Receiver



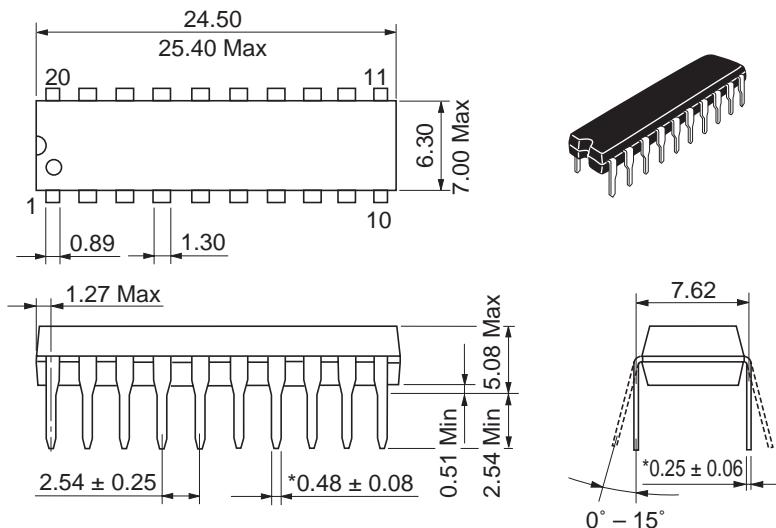
Package Dimensions

As of January, 2003
Unit: mm



Package Code	DP-20N
JEDEC	—
JEITA	Conforms
Mass (reference value)	1.26 g

Unit: mm



*NI/Pd/AU Plating

Package Code	DP-20NEV
JEDEC	—
JEITA	Conforms
Mass (reference value)	1.26 g

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